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REVIEW ARTICLE

Review of fabrication methods of large-area transparent graphene electrodes for industry

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Abstract Graphene is a two-dimensional material showing excellent properties for utilization in transparent electrodes; it has low sheet resistance, high optical transmission and is flexible. Whereas the most common transparent electrode material, tin-doped indium-oxide (ITO) is brittle, less transparent and expensive, which limit its compatibility in flexible electronics as well as in low-cost devices. Here we review two large-area fabrication methods for graphene based transparent electrodes for industry: liquid exfoliation and low-pressure chemical vapor deposition (CVD). We discuss the basic methodologies behind the technologies with an emphasis on optical and electrical properties of recent results. State-of-the-art methods for liquid exfoliation have as a figure of merit an electrical and optical conductivity ratio of 43.5, slightly over the minimum required for industry of 35, while CVD reaches as high as 419.

Keywords transparent electrodes, graphene, liquid exfoliation, chemical vapor deposition (CVD)

1 Introduction

First observations of few-layer graphene was done by Novoselov et al. in 2004 when they isolated it from highly pyrolytic graphite [1] by mechanical exfoliation. Theoretical work by Peierls [2] and Landau [3] in the 1930s suggested that two-dimensional films are not stable, and their work was later further improved by Mermin in 1960s [4]. In 1980s, Nelson and Peliti showed that while twodimensional sheets are not stable, extending the sheet into the third dimension by buckling can make the film stable [5].

Graphene is a two-dimensional allotrope of carbon with a hexagonal lattice with multiple intriguing properties for

future electronics. It has a very long mean free path of charge carriers, in the order of tens of microns in low temperatures (< 130 K) [6] and up to 1 μ m in roomtemperature [7], providing the possibility of devices using ballistic transport. It has a room-temperature electron mobility of $> 10^5$ cm²/(V·s) [8] and theoretical mobility of 2×10^6 cm²/(V · s) [9]. Very high stiffness of up to 1 TPa [10,11] and intrinsic strength of 130 GPa [12], but is still flexible due to its two-dimensionality. Monolayer graphene absorbs only 2.3% of light in the visible range, which is solely defined by the fine structure constant [13], and has a high thermal conductivity of $> 3000 \text{ m}^{-1} \cdot \text{K}^{-1}$ [14] with a very good chemical stability [15-17]. It also exhibits interesting quantum mechanical phenomenon, such as, the breakdown on adiabatic Born-Oppenheimer approximation [18], room-temperature guantum Hall effect [19,20], fractional quantum Hall effect [21] and a possibility of quantum anomalous Hall effect [22].

Unfortunately, many the aforementioned properties require extreme conditions or special, non-scalable, fabrication methods. Most of the graphene studied was derived from micromechanically exfoliated graphene, which is a non-scalable, low-yield and very mechanical process. Furthermore, in order to obtain these values, hexagonal boron nitride (hBN) is used (or suspended graphene) as graphene substrate, which is also fabricated via micromechanical exfoliation.

Nowadays, the most common material for transparent electrodes is tin-doped indium-oxide (ITO). ITO has good optical transmission (>90%) in the visible range and sheet resistances of 10–30 Ω /sq [23]. A significant downside to ITO is that indium is a rare-earth material, and hence, expensive. Generally, crystalline ITO is fabricated by magnetron sputtering on glass with a post-deposition high-temperature annealing process to initialize crystallization, which hinders the use of ITO on plastics [24]. Furthermore, ITO is prone to cracks at small bending radii [25] even if polycrystallinity is achieved [26,27].

This review will focus on chemical vapor deposition

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(CVD) and liquid exfoliation as fabrication methods for transparent graphene electrodes where sheet resistance R_s and optical transmission T are main parameters in evaluation. A standard figure of merit, the ratio between electrical and optical conductivity, is calculated via

$$\frac{\sigma_{\rm DC}}{\sigma_{\rm OP}} = \frac{Z_0 \sqrt{T}}{2R_{\rm s}(1 - \sqrt{T})},\tag{1}$$

where σ_{DC} and σ_{OP} are electrical and optical conductivity, Z_0 is the impedance of free space, *T* is transmission and R_s is sheet resistance. While review articles on the field of two-dimensional materials (specifically graphene) are abundant, there are few that are written from an industrial viewpoint. Moreover, few of them adopt a specific figure of merit through which different methods are ranked. Here we remedy the situation by using a commonly applied figure of merit to a wide range of articles where the applied fabrication methods are potentially scalable to industrial needs as per authors' point of view.

Liquid exfoliation and CVD have been selected for this review due to the quality of the graphene produced, ease of use, throughput, and capabilities for large-area production and they both have been extensively studied. The methods complement one another, where CVD produces generally higher quality graphene, it also has higher capital costs and has more limited large-area capabilities. Liquid exfoliation deals with solvents (often aqueous) and therefore the area of produced graphene is not nearly as limited, it also enables easy integration to polymers and other materials as additives, enhancing their capabilities. Moreover, CVD often produces monolayers and it can be challenging to scale vertically, whereas achieving multilayers is easier in liquid exfoliation because the coating procedure is simpler than manually transferring multiple monolayers of graphene.

2 Liquid exfoliation

Exfoliation methods consist of two groups: liquid exfoliation and mechanical exfoliation. In mechanical exfoliation, a peeling force, commonly via an adhesive tape, separates graphitic layers from a dry graphite sample [28]. In comparison, liquid exfoliation uses vigorous agitation in a liquid resulting in separated graphitic layers in solution.

Liquid exfoliation is defined as the act of separating layers of material in a liquid solvent by exposing it to high shear forces. Liquid exfoliation takes advantage of the layered nature of graphite which has strong in-plane bonds but weaker van der Waals bonds out-of-plane that couple each layer. As a result, shearing forces can easily separate the layers down to individual monolayer sheets (graphene).

The most common method of liquid exfoliation is via agitation by sonication (see Fig. 1(a)), but there exist multiple different methods. Sonication creates highly energetic acoustic cavitation, where the resulting microbubbles produce pressures up to 500 atmospheres [29], hence providing more than enough shear force required for exfoliation [30]. Another agitation method is high-shear mixing, which involves a rotor-stator type of system, see Fig. 1(b). In this method, high shear-rates induce interlayer sliding of material, providing exfoliation [31].

There are several methods to increase exfoliation yield in agitation-based liquid exfoliation. The optimized choice of solvent is important because its function is to provide an environment where a stable dispersion of exfoliated material is possible. Organic solvents, such as, dimethylformamide (DMF) [34], N-methyl-2-pyrrolidone (NMP) [35], dichlorobenzene [36], and many others [37] fill these categories. Bunch et al. used liquid exfoliation in dichlorobenzene to produce few layer graphene flakes already in 2005 [36] but it was not until 3 years later when Hernandez et al. [35] were able to produce single layer graphene by using NMP, a solvent first introduced in liquid exfoliation carbon nanotubes [38], to produce graphene via sonication. Around this time, Coleman [39] investigated the reason why the aforementioned solvents are superior, and observed that well performing solvents have a surface tension of ~40 mJ/m². An even better criterion for a good solvent is the Hildebrand solubility parameter, which should be close to 23 MPa. This was later shown by Hernandez et al. [37], who tested 40 different solvents for graphene. Unfortunately, many of these organic solvents possess high boiling points, making them hard to remove after dispersion [34,35,40-43].



Fig. 1 (a) A possible route for cavitation-bubble induced liquid exfoliation of graphite to graphene. Adapted from Ref. [32]. (b) High-speed shear mixing setup with a rotor, stator and mixing head visible. Adapted from Ref. [33]

Another method to increase yield is to use surfactants to decrease the graphite interflake attraction. A surfactant method is desirable as it allows the utilization of solvents that are less toxic and have lower boiling points, e.g., water, methanol and isopropanol. There are multiple different surfactant types, such as ionic/non-ionic, aromatic/non-aromatic, polymers [44], that work by decreasing surface energy of graphite and therefore raising the number of usable liquid mediums. Disadvantages are that the residual surfactants are hard to remove and commonly deteriorate the electrical properties of graphene. A more indepth review of surfactant based liquid exfoliation is provided in Ref. [44].

Intercalation is a liquid exfoliation method where intercalating agents are used to increase the interlayer distance of graphitic layers, thereby decreasing the bond strength and making graphite easier to exfoliate. For instance, in electrochemical exfoliation, intercalants, such as ionic liquids [45], are used inside an electrochemical cell. A potential difference provides a charge to a graphite electrode, attracting intercalating species (cations or anions, depending on charge polarity) within the graphite sheets. The exfoliation happens through subsequent mechanical agitation or through spontaneous exfoliation via e.g., water splitting into oxygen/hydrogen gas due to an electrochemical reaction.

Low concentrations of graphene are problematic for fabricating continuous sheets for transparent electrodes because multiple depositions are needed to produce a percolating network, so it is important to have sufficient yield. Hernandez et al. [35] produced approximately 0.01 mg/mL of multilayer graphene (< 6 layers) with an approximate monolayer yield of ~1 wt.% with relation to the original graphite mass. The achieved sheet resistance was 5.1 k Ω /sq with 42% transmittance after a 250°C annealing in Ar/H₂ atmosphere. The concentration was further increased to 1.2 mg/mL [46] (or even up to 2 mg/mL [39]) by long-time sonication (460 h) and centrifugation where it was concluded that the ratio between monolayer-concentration and centrifugation time follows \sqrt{t} behavior, whereas flake width and length follow $t^{-1/2}$, where t is the centrifugation time.

Highly concentrated graphene solutions were prepared by Liang and Hersam, where ethyl cellulose (surfactant) enhanced ethanol was used as a solvent [40]. A ~0.1 mg/mL concentration was achieved by few hour sonication and centrifugation; however, the concentration was increased by iterative solvent exchange to 1.02 mg/mL. The corresponding sheet resistance was measured to be roughly 6 kΩ/sq with optical transmittance of ~70% at 550 nm ($\sigma_{\rm DC}/\sigma_{\rm OP} = 0.16$, see Eq. (1)) after 400°C annealing. This method does not require hundreds or hours of sonication to acquire high-concentrations and does not use toxic NMP as a solvent. Recently, Li et al. used sonication with sodium citrate in NMP/water cosolvent to achieve few-layer graphene concentrations as high as 0.71 mg/mL with 4 h of sonication and 30 min of centrifugation [47]. Mean conductivity of annealed graphene (500°C for 2 h) was 1.4×10^4 S/m, roughly twice that of the results by Hernandez et al. [35], with oxygen contents of ~2.39%. No transmittance or sheet resistance data was provided.

Unfortunately, removal of surfactants generally requires high-temperature annealing, and they introduce defects to the graphene structure due to them being electrically insulating [44]. In order to remedy the introduction of defects, Zhang et al. used pyrene-based surfactants (Py- NH_2 and $Py-SO_3$ [48] due to their ability to heal graphene defects during annealing [49]. It was reported that the initial sheet resistance (using Gr-Py-NH₂) was $10^8 \Omega/sq$, which subsequently decreased to $10^4 \Omega/sq$ by $1000^{\circ}C$ annealing. Better results were observed with Py-SO₃ surfactant, where the sheet resistance decreased down to 778 Ω /sq. Both surfactants had transmittances of ~90% $(\sigma_{\rm DC}/\sigma_{\rm OP} = 4.5 \text{ and } 0.35 \text{ for Py-SO}_3 \text{ and Py-NH}_2$, respectively) on quartz substrates and with graphene concentrations of ~0.4 mg/mL. Transmittances of ~40% were achieved on polydimethylsiloxane (PDMS) with sheet resistances of $10^3 \Omega$ /sq. Again, high-temperature annealing is used to remove the adsorbed surfactants. An alternative method for circumventing this was applied by Tung et al., who used graphite oxides (GOs) as surfactants for pristine graphene [50] with the idea that the GOs only assist during exfoliation, after which they are removed by centrifugation and the graphene flakes are suspended in an appropriate solvent. The GOs are only attached non-covalently to graphene, hence they are easy to remove. Flakes with lateral dimensions of 5-10 µm were achieved by this method and transparent electrodes on glass measured sheet resistance of 668 Ω /sq with transmittance of 80% (σ_{DC}/σ_{OP} = 2.39).

Another method for circumventing the long processing time of high-concentration graphene solutions by sonication is to use shear mixing instead of sonication. Furthermore, energy requirements for shear mixing scale better than sonication, which is of interest to industrialscale production. Paton et al. introduced this method and acquired sheet resistances of $10^2 \Omega/sq$, at sheet thicknesses of few hundred nanometers (no transmission data) [32]. Using this as a basis, Majee et al. were able to produce concentrated graphene ink (3.2 mg/mL) and use it in inkjet printing system to achieve sheet resistance of $\sim 260 \Omega/sq$ at 85% transmittance after annealing in ambient at 350°C, giving a figure of merit $\sigma_{\rm DC}/\sigma_{\rm OP}$ of 8.6 [51]. More recently, Shin et al. used high-shear mixing in a aqueous sodium cholate (NaC) solvent with a direct transfer process based on the evaporation of isopropyl alcohol [52]. They were able to achieve flakes with average thickness of four layers (50% of flakes less than four layers) with average lateral size of ~110 nm. The resulting

sheet resistances were high, from 2×10^3 to $8 \times 10^6 \Omega/sq$ with transmittances of 44.5% to 73.1%, respectively, resulting in figures of merit in between ~0.25 and ~1.4×10⁻⁴ without any annealing.

Methods other than based on mechanical agitation can be used as well to produce high-concentration graphene solutions through liquid exfoliation. In addition, agitationbased processing is inherently limited by mechanical properties (e.g., blade diameter, rotation speed, energy transfer) which can be avoided in some non-agitationbased methods. After the discovery of electrochemical functionalization of carbon nanotubes using ionic-liquids [53], Liu et al. introduced electrochemical exfoliation of graphite via ionic-liquids [45], however, the resulted sheets were quite small (lateral size $< 1 \mu m$). Su et al. later improved upon this by combining sulfuric acid, used in production of expanded graphite, and electrochemical exfoliation [54]. Multiple aqueous electrolytes (HBr, HCl, HNO_3 , and H_2SO_4) were tested in order to produce electrochemically exfoliated graphene. It was observed that H_2SO_4 produced the best results in mere minutes. All of the produced graphene flakes had thicknesses less than 3 nm (graphene interlayer distance was measured to be 0.45 nm and double-layer being 1.5 nm) and lateral sizes of microns to tens of microns, with total yield of 5-8 wt.% (0.085 mg/mL). By using interface aggregation method. thin films of ~3.8 nm thickness were produced with transmittances of ~96%. The initial sheet resistance was 43 k Ω /sq which decreased to by HNO₃ doping, and further decreased via 450°C annealing in H₂/Ar atmosphere to 210 Ω /sq, resulting in $\sigma_{\rm DC}/\sigma_{\rm OP}$ = 13.9 and 43.5 for nonannealed and annealed electrodes, respectively. Unfortunately, considerable amounts of defects were observed from Raman data, as a large disorder-peak is clearly visible.

Liu et al. further investigated electrochemical exfoliation by using aqueous solution of Na₂SO₄ with and without sonication assistance [55]. It was found out that the sonication further decreased the average flake thickness (from four to two layers) and number of defects considerably, increasing capacitor energy and power performances, but non-sonicated graphene showed better results for transparent electrodes. Non-sonicated graphene had a transmittance of 75.8% after 200°C annealing in air with 4.28 k Ω /sq sheet resistance, which dropped drastically to 440 Ω /sq after 400°C annealing, corresponding to $\sigma_{\rm DC}/\sigma_{\rm OP} = 2.88$, with oxygen contents of 16.3 and 13.0 at.% for non-annealed and annealed samples (sonication had little effect in oxygen content). The number of defects from oxidation by intercalating ions is problematic as they decrease the quality of the acquired thin film. Parvez et al. were able to diminish this issue by using inorganic salts as an electrolyte for electrochemical exfoliation [56]. The most efficient electrolyte tested was $(NH_4)_2SO_4$, yielding graphene with much less oxygen content than the aforementioned Liu et al. [55], with a decrease from

~13.0 to 5.5 at.%. The final result being a sheet resistance of 330 Ω /sq and a transmittance of 87% after doping with HNO₃ and annealing at 300°C, giving a figure of merit (σ_{DC}/σ_{OP}) of 4.8.

Recently, some new techniques have been developed for electrochemical exfoliation. Zhang and Xu achieved a significant yield increase (and production rate) by using a two metal-mesh wrapped graphite electrodes in a tetrabutylammonium perchlorate/polycarbonate (TBA ClO₄/ PC) electrolyte, and utilizing both, cathodic and anodic exfoliation at the same time [57]. Yields of 85% and 48% and oxygen contents of approximately 4.7% and 5.4% were achieved for cathodic and anodic reactions, respectively, with 80% of flakes having thicknesses from one to three layers with a relatively small the Raman disorder peak $(I_{\rm D}/I_{\rm G} < 0.08)$. Unfortunately, no transmittance data was measured and the only electrical measurements were conductivity measurements of graphene paper (> 3×10^4 S/m) and sheet resistances of graphene ink (10 mg/mL) from 4 k Ω /sq with one printing repetition down to 11 Ω /sq with six repetitions.

Another innovation was realized by Roscher et al., who used high-voltage cathodic exfoliation with boron-doped diamond electrodes to realize yields over 70% [58]. The electrolyte was tetrabutylammonium hexafluorophosphate/ polycarbonate (TBA PF₆/PC) and the specialized electrode was required to achieve the high potentials without the electrode dissolving. It was observed that the few-layer graphene yield increased substantially from 10% to over 70% when the applied voltage was increased from -30 to -60 V. Sheet resistances of 1.6–3.2 kΩ/sq were measured at ~70% transmittance (maximum $\sigma_{\rm DC}/\sigma_{\rm OP} = 0.61$) after thermal annealing at 800°C with $I_D/I_G < 0.2$, but with no data on oxygen contents. Highest figure of merit was achieved with 48% transmittance which had sheet resistance of 550 Ω/sq, resulting in $\sigma_{\rm DC}/\sigma_{\rm OP} = 0.78$.

The previous methods use cathodic or anodic reactions to force ions in between graphite sheets, thereby increasing the interlayer distance. This can also be done purely by chemical means, removing the complications that come from an electrochemical cell. Oxidizing graphite via Hummer's method is a common way of increasing the interlayer distance of graphite, which is discussed in more detail later in this work. Unfortunately, oxides introduce defects due to their insulating properties, which can be a problem with electrochemical exfoliation as well. In order to increase the interlayer distance of graphite without using oxides, Park et al. used ternary KCl-NaCl-ZnCl2 salts in a eutectic system to produce intercalation, separating graphene flakes in moderate temperatures of ~300°C in 10 h [41]. Graphene yields of ~60% were achieved (no mention of concentration) after a short (30 min) sonication. Sheet resistance of ~930 Ω /sq with ~75% transmittance (at 633 nm), corresponding to $\sigma_{\rm DC}/\sigma_{\rm OP}$ = 1.3, were measured after 300°C annealing in hydrogen atmosphere and using modified Langmuir-Blodgett method, see Fig. 2(c), for



Fig. 2 (a) Reduced graphene oxide spray-coated on a 4-inch quartz wafer. Adapted from Ref. [66]. (b) Rod-coated room-temperature reduced graphene oxide transferred on a flexible PET substrate. Adapted from Ref. [69]. (c) Scheme for Langmuir-Blodgett method where a graphene film forms at the air-water-interface. The substrate is pulled upwards while the film is under steady compression. The film adheres to the substrate as it is pulled, and a monolayer transfer is achieved. Adapted from Ref. [41]

graphene coating. This type of chemical intercalation method is not limited by mechanical properties, merely the size of processing container, which makes it easier to scale.

Another source of graphene is from conversion of graphite to graphite oxide (GO). The conversion is commonly performed using Hummer's method (or modified Hummer's method) [59–61], but there exist multiple other methods as well [62]. The conversion relies on heavily oxidizing compounds, e.g., potassium permanganate (KMnO₄) and intercalants, such as sulfuric acid (H_2SO_4) . GO sheets are easier to exfoliate because the interlayer distance is already increased compared to graphite. In addition, GO is a stable suspension in a wider range of solvents (e.g., aqueous solvents) which is achieved due to the hydrophilic nature of the sheets. GO is intrinsically defective and electrically insulating due to surface oxides, which cannot be fully reversed via reduction [63], furthermore, reduction commonly uses high temperatures and toxic chemicals [15,64–68], making it complicated and expensive.

Even though GO is inherently defective due to oxides, it is extremely easy to exfoliate, making it very commonly used material for producing graphene via liquid exfoliation. Whereas pristine graphene flakes produced by liquid exfoliation are generally hundreds of nanometers to few microns in lateral size, GO flakes can be up to 200 µm, as was shown by Zheng et al., who used intercalation based exfoliation with multiple consecutive centrifugations [15]. Reduction was done by annealing in 400°C and 1100°C subsequently. This produced films with sheet resistance of ~600 Ω /sq with 550 nm transmittance of 86% ($\sigma_{\rm DC}/\sigma_{\rm OP}$ = 4.01), which were improved via HNO₃ (3 h) and SOCl₂ (24 h) doping to 459 Ω /sq, 90% and 7.59 for sheet resistance, transmittance and figure of merit ($\sigma_{\rm DC}/\sigma_{\rm OP}$), respectively. The sheet resistance stabilized to $\sim 570 \Omega/sq$ $(\sigma_{\rm DC}/\sigma_{\rm OP} = 6.11)$ after four months.

A high-temperature reduction step has been investigated by Becerril et al. [68], who used thermal treatments of 400°C–1100°C and a combination of hydrazine vapor. It was observed that the best results are achieved via 1100°C thermal treatment (HT), but a combination of hydrazine vapor and low-temperature annealing at 400°C (H-LT) is also utilizable due to the reduced temperatures. HT produced films with ~4 k Ω /sq sheet resistance at ~82% transmission (550 nm) while H-LT resulted with sheet resistance of ~40 k Ω /sq and ~78% transmission, giving figure of merits of 0.56 and 0.036 for HT and H-LT, respectively. Further improving on this, Wang et al. used cellulous ester filter membranes with vacuum filtering and combined the hydrazine, low-temperature annealing (400°C) and high-temperature annealing (1100°C) (H-LT-HT) [64]. H-LT transmittance was ~87% with sheet resistance of ~50 kΩ/sq ($\sigma_{\rm DC}/\sigma_{\rm OP} = 0.05$) or ~60% and ~6 k Ω /sq ($\sigma_{\rm DC}/\sigma_{\rm OP} = 0.11$). The combination (H-LT-HT) resulted in much better properties of ~74% transmittance and 2 kΩ/sq sheet resistance ($\sigma_{\rm DC}/\sigma_{\rm OP} = 0.58$).

The high temperatures required for the reduction of GO are problematic for flexible electrodes based on polymer substrates due to their low melting points, and because it increases fabrication costs. In order to decrease the reduction temperature, Pham et al. mixed graphite oxide with hydrazine monohydrate and spray-deposited this mixture on pre-heated quartz substrates [66] instead of using hydrazine vapor and high-temperature annealing after deposition for reduction. It was reported that a considerable reduction happened already at temperatures of 240°C with a final sheet resistance of 2.2 k Ω /sq with transmittance of 84% ($\sigma_{\rm DC}/\sigma_{\rm OP} = 0.94$), see Fig. 2(a). Even lower reduction temperatures were achieved by Wang et al. [69], who used room-temperature reduction in hydrogen atmosphere with a palladium catalyst. Small amounts of palladium chloride (PdCl₂) was added into the GO solution before rod-coating and drying a polyethylene terephthalate (PET) substrate in ambient air, see Fig. 2(b). GO was reduced in hydrogen atmosphere in ambient temperature for 6 h. A thin film with a sheet resistance of 1.68 k Ω /sq was achieved with transmittance of 64.6% ($\sigma_{\rm DC}/\sigma_{\rm OP}$ = 0.46). Alahbakhski et al. were able to come close to that of the aforementioned Wang et al. results by combining chemical reduction by hydroionic acid (HI) and a

subsequent lower temperature thermal treatment (700°C) [67]. They achieved sheet resistance of 1.1 kΩ/sq with 89% transmittance ($\sigma_{DC}/\sigma_{OP} = 2.86$) using chemical reduction with the thermal treatment; and using only chemical reduction, sheet resistance and transmittance of 1.7 kΩ/sq, and 75% ($\sigma_{DC}/\sigma_{OP} = 0.72$) were achieved, respectively. Table 1 includes a collection of all the discussed results, as well as multiple others. The best results for the figure of merit are 45.5 and 13.9 via electrochemical exfoliation; however, most of the obtained values do not reach the minimum required values for industry ($\sigma_{DC}/\sigma_{OP} = 35$) [70]¹⁾. It is worth noting that very few of the discussed liquid exfoliation methods used any kind of doping.

Doping can potentially double, or triple, the figure of merits, after which the electrochemical methods could reach values above 100. More details on graphene doping are presented in the next section.

3 Chemical vapor deposition

CVD is a process of depositing a compound in a controllable fashion on surfaces via thermal and catalytic decomposition of precursors. This initiates a chemical reaction between the decomposed products and a substrate in order to produce a desired result. The result can be, for

Table 1 Summary of liquid exfoliated graphene based transparent electrodes, where R_s , T, and σ_{DC}/σ_{OP} refer to sheet resistance, transmittance (at 550 nm) and figure of merit, respectively. Annealing column mentions whether high-temperature annealing is done and at what temperature. Exfoliation method explains which method is used and whether surfactants are used; if only GO is mentioned, then no agitation is used for exfoliation

$R_{\rm s}/(\Omega \cdot { m sq}^{-1})$	T/%	$\sigma_{\rm DC}/\sigma_{\rm OP}$	annealing/°C	exfoliation method	Ref.
100	90	35	_	-	minimum industry requirement [70]
22500	62	0.03	250	surfactant + sonication	[71]
40000	78	0.036	400 ^{a)}	GO + sonication	[68]
5100	42	0.069	250	sonication	[35]
6000	60	0.11	400 ^{a)}	GO + sonication	[64]
6000	70	0.16	_	surfactant + sonication	[40]
1500	44	0.25	_	shear	[52]
3200	70	0.30	600	electrochemical	[58]
4000	76	0.32	500	surfactant + sonication	[72]
5000	80	0.32	800	surfactant + GO + sonication	n [65]
1000	47	0.41	500	surfactant + sonication	[72]
1680	65	0.46	_	GO + sonication	[69]
4000	82	0.56	1100	GO + sonication	[68]
2000	74	0.58	$400 + 1100^{a}$	GO + sonication	[64]
550	48	0.78	600	electrochemical	[58]
1700	75	0.72	_	GO	[67]
2200	84	0.94	1100	GO + sonication	[66]
930	75	1.3	300	intercalation	[41]
668	80	2.39	350	surfactant + sonication	[50]
1100	89	2.86	700	GO	[67]
440	76	2.9	400	electrochemical	[55]
600	86	4.01	400 + 1100	intercalation + GO	[15]
778	90	4.5	1000	surfactant + sonication	[48]
330	87	4.8	300	electrochemical	[56]
459	90	7.59	$400 + 1100^{b)}$	intercalation + GO	[15]
260	85	8.6	350	shear	[43]
657	96	13.9	450	electrochemical	[54]
210 ^{a)}	96	43.5	450	electrochemical	[54]

Notes: a) Hydrazine vapor + annealing. b) Chemical doping via HNO3 and SOCl2.

The authors of the reference were collaborating with Hewlett Packard (HP) in development of transparent electrodes and HP specified that the minimum required values for industry are 100 Ω/sq with 90% transmittance.

example, a molecular coating with a specific crystal structure or a complex compound agglomerates on predetermined nucleation sites.

There are commonly four different terms that are used in describing CVD equipment: hot wall, cold wall, horizontal geometry and vertical geometry. In a hot wall reactor, the substrate is heated by heating the reactor walls. Here the reaction zone, the area where chemical reactions take place, is large. Whereas in a cold wall reactor, the substrate is heated directly, and the chemical reactions take place only on the substrate. Horizontal geometry is the most common one, which is a horizontal quartz tube with heating elements surrounding it in the middle. Here precursor and carrier gases flow laterally over the sample, through the reaction zone, see Fig. 3(a). In a vertical geometry, the gases flow vertically towards the substrate. Usually horizontal furnaces are hot wall furnaces and vertical furnaces are cold wall. Pressure also differentiates CVD equipment: low- and atmospheric pressure CVD are the most common, but ultra-high vacuum and highpressure CVDs are also an option.

Commonly in CVD of graphene, a catalytic substrate (generally a transition metal [73]), such as copper or nickel, is heated to ~1000°C under hydrogen (H₂) and argon (Ar) flow in a low-pressure $(10^{-3}-10^{-2} \text{ bar})^{1}$ system. Afterwards, a hydrocarbon precursor is introduced into the system and it goes through a catalytic dehydrogenation due to the elevated temperatures.

A common hydrocarbon source is methane (CH₄) because its stability allows higher temperatures, hence provoking higher quality graphene growth. Other gas phase hydrocarbons, such as acetylene (C_2H_2) and ethylene (C_2H_4), can be used at lower temperatures (600°C–800°C [74,75] and 800°C–900°C [76–78], respectively). Graphene can be grown via multiple other hydrocarbon sources, such as polymethyl methacrylate (PMMA), sucrose, fructose [79], silicon carbide via sublimation [80], propane and ethane [81] and polycyclic aromatic hydrocarbons [82]. In the end, multiple different routes for graphene CVD exist: plasma enhanced CVD (PECVD), using different hydrocarbons, atmospheric

pressure CVD, ultra-low pressure, deposition on insulating surfaces and many others. A very throughout review of these methods as well as more in-depth discussion of transfer methods and growth on multiple substrates can be found in Ref. [83].

In the case of copper and methane, the hydrocarbon adsorbs on the substrate and go through a series of dehydrogenation steps: $CH_4(g) \rightarrow CH_4(s) \rightarrow CH_3(s) +$ $H(s) \rightarrow CH_2(s) + 2H(s) \rightarrow CH(s) + 3H \rightarrow C(s) + 4H(s),$ where (s) and (g) represent solid (adsorbed) and gaseous phases. Here, the rate-limiting step is the last step of $CH(s)+3H(s) \rightarrow C(s)+4H(s)$ with an activation energy of 1.5–1.9 eV [73,85]. However, experimentally the entire graphene growth process: adsorption, dissociation, diffusion and growth (see Fig. 3(b)) has an energy barrier of 1.5-3.1 eV [86-89], suggesting that nucleation is the final rate-limiting step, as analyzed by Shu et al. [90]. It was argued that the energy barrier for carbon incorporation process can be as high as ~ 2.5 eV for Cu(110) but it can be lowered down to 0.8 eV by using Cu(111), even though Kim et al. did not observe this experimentally [86]. More complications arise from the fact that the methane dissociation is not straightforward $CH_4(g) \rightarrow CH_4(s) \rightarrow$ $CH_3(s) + H(s) \rightarrow CH_2(s) + 2H(s) \rightarrow CH(s) + 3H \rightarrow C(s) +$ 4H(s), but intermediate compounds, such as acetylene (C_2H_2) , ethylene (C_2H_4) , and ethane (C_2H_6) , are formed on the copper substrate as well [84,91].

The hydrocarbon dissociation energy and the substrate's catalytic power define the growth temperature. Dehydrogenation energy is different for each carbon source, e.g., dissociation energy of CH₃–H (first dehydrogenation step of CH₄) is 4.85 eV in gas phase [92], (it is the most stable hydrocarbon up to ~1000°C [93]) but can be reduced to < 1 eV, on substrates such as Pt [94], Ru, Os, Rh, Ir and Pd, whereas for Cu it is slightly higher of 1.12 eV [73].

The dissociated hydrocarbon species diffuse on the substrate until the concentration of active carbon species is high enough to initiate nucleation. The nucleation spots grow outwards until they coalesce with other nucleation spots and cover the entire surface [95,96]. This deliberate catalyst poisoning will stop the surface catalytic reactions



Fig. 3 (a) Schematic picture of a horizontal quartz furnace where gases flow laterally over the substrate in a reaction zone surrounded by heating elements. (b) Simplified scheme of graphene growth in CVD. Hydrocarbons adsorb on the surface (1), dehydrogenate (2), nucleate and grow (3), diffuse to bulk if high carbon soluble substrate (4), diffuse out (5), and segregate (6). Adapted from Ref. [84]

from taking place as the copper surface is no longer exposed to the hydrocarbons and therefore the catalytic decomposition stops. Surface catalytic growth is a common term for this growth mechanism and it takes place in low solubility transition metals, such as copper (~7.4 at.ppm) [97].

In contrast, some transition metals have a high carbon solubility, such as nickel (1.5 at.%) [98,99], and the growth mechanism behind these substrates is called precipitation growth. In precipitation growth, the active carbon species absorb into the bulk of the substrate, and precipitate back to the surface when the substrate cools, see Fig. 3(b). After precipitation, the carbon species diffuse and nucleate, forming graphene [100]. Achieving monolayer growth via precipitation method is difficult because there are no mechanisms that stop subsequent layers from growing under the initial graphene layer. This method also introduces the rate of cool down as an important optimization parameter. Even though the aforementioned process is a common explanation of the precipitation mechanism, there exist nuances to it, such as that the amount of surface catalytic growth is still crucial for highquality graphene growth [101], and that the active carbon species inside the bulk already form carbon chains and irregular carbon clusters prior to surface nucleation [102].

One of the first CVDs of multilayer-graphene was done by Kim et al. [98] using thin (300 nm) nickel layer on SiO₂ and methane as the hydrocarbon precursor. Two different graphene transfer methods were introduced: PDMS stamping and SiO₂ etching method. In the former method, a PDMS stamp is pressed on the graphene/nickel stack and the nickel layer is etched away in FeCl₃, then the PDMS/ graphene stack is pressed on an arbitrary substrate and the PDMS is peeled off. SiO₂ method involves etching the oxide layer in hydrogen fluoride (HF) solution, leaving the nickel/graphene stack intact. Afterwards the stack is scooped off from the solution on an arbitrary substrate and the nickel layer can be removed with FeCl₃. The results were sheet resistance of with 76% transmittance at 550 nm ($\sigma_{DC}/\sigma_{OP} = 4.6$).

However, the PDMS stamping method is a very manual technique only suitable for small samples. In order to remedy this, Verma et al. developed a quick and easy large-scale graphene transfer technique to flexible PET substrates [103]. Graphene synthesized on copper foil via CVD was transferred to PET by hot press lamination, where the copper/graphene stack is merely fed through an office laminator, which adheres a PET film on top of the graphene layer. Afterwards the copper layer was removed in FeCl₃ and graphene on a flexible PET substrate is achieved. Foldability was gauged via measuring the resistance as a function of the bending radii and it was found out that the resistance increase is only ~20% and it recovers completely after unbending. Measured sheet resistance was 1174 Ω /sq with transmittance of 88.8% ($\sigma_{\text{DC}}/\sigma_{\text{OP}} = 2.62$).

Another way to circumvent issues with the transfer

process is to directly grow graphene on an insulating surface. Kalita et al. grew graphene directly on quartz by utilizing camphor as the hydrocarbon source [104]. A horizontal furnace with two heating elements was used. First element was kept at 200°C and was used to evaporate the camphor and the second element provided gas-phase pyrolysis at 800°C–900°C, where the quartz substrates were placed. A highly defective few-layer graphene was grown with sheet resistance of 1.645 kΩ/sq and transmittance of 81% at 550 nm.

A way to increase the productivity of a standard horizontal furnace was investigated by Nagai et al., where a high-reactivity hydrocarbon source, acetylene (H₂C₂), was used instead of the more stable methane (CH₄) [105]. Multiple rolled copper foils were placed inside one another in a horizontal hot-wall furnace and graphene was grown in less than 20 min (15 min heating, 1 min annealing and 1.5 min growth) in 975°C. The method produced 1–2 layers of graphene with sheet resistances of 780–1680 Ω /sq and transmittances of 94.8%–96.7% (σ_{DC}/σ_{OP} = 4.76–11.45). The sheet resistances decreased down to 299 Ω /sq after p-doping with HNO₃ vapors with only 0.2% transmittance increase, giving a figure of merit of 28.4.

Another method for increasing productivity is to use a roll-to-roll production instead of a batch production. Rollto-roll production has the capabilities of fabricating graphene in very large quantities in a continuous manner. Bae et al. used an 8-inch wide horizontal furnace with a ~7.5-inch suspended quartz tube wrapped with copper foil to realize very large-area graphene production [106]. Afterwards the copper/graphene stack was adhered to thermal release tape in between two rollers, and finally the copper layer is etched in ammonium persulfate solution. The graphene can be transferred from the thermal release tape to any substrate by exposing it to mild temperatures of 90°C-120°C. A four-layer graphene electrode on PET substrate with HNO₃ doping has a sheet resistance of 30 $\Omega/$ sq with 90% transmittance. Single-layer graphene shows values of ~110 Ω /sq and 97.4% for sheet resistance and transmittance, respectively. These values result in figures of merits of 116 and 135, respectively.

Graphene is often transferred on flexible polymers in order to produce flexible transparent electrodes. Previously mentioned polymers, PET and PDMS, are common choices for this. Kim et al. used ionic liquid based cellulose as a flexible polymer for graphene based NO₂ sensors due to it having chemical properties that enable sensitive and selective gas sensing [107]. Cellulose is also an eco-friendly substrate with good thermal and chemical stabilities, and excellent solubility. The effect of cellulose on the graphene defect density was observed to be small due to the smaller sheet resistance of graphene/cellulose film in comparison to graphene/SiO₂ film; Raman disorder peak (d-peak) could not be used in this effect because the cellulose peak is superimposed on the graphene disorder peak. The fabricated film had a sheet resistance of 320 Ω /sq with transmittance of 98% at 550 nm, resulting with $\sigma_{DC}/\sigma_{OP} = 58.02$.

Another less common polymer, CVD parylene, has been used as a supporting polymer for flexible electrodes by Kim et al. [108]. Copper foil was removed from parylene/ graphene/copper stack via bubbling transfer method, where hydrogen bubbles peel away the copper foil from graphene in an electrochemical (NaOH) solution. The pristine graphene sheet resistance of 150 Ω /sq was reduced to 100, 30 and 20 Ω /sq with Kl, AuCl₃ and HNO₃ dopants with transmission of ~96.5%. This led to extremely high figure of merit values of ~420.

Even though the previously mentioned results focus on the transfer process or substrates, the growth process itself is not perfect and it introduces defects as well, such as grain boundaries due to the polycrystalline nature of the growth process. To reduce the effects of grain boundaries, pin-holes and cracks. Park et al. applied an interesting defect healing technique, where gold nanoparticles were selectively transferred to defective sites via electroplating [109]. The charge distribution of graphene is dependent on its defect distribution; therefore, current densities within the gold chloride (AuCl₃) electroplating solution change near defects, allowing selective transfer of gold nanoparticles to defected areas. This is shown schematically in Fig. 4. The transferred nanoparticles were capped by mechanically transferring a second graphene layer on top of the nanoparticles. The capping layer was found to be important, as the increase of sheet resistance (roughly three orders of magnitude) without it was nearly identical to that of pristine graphene under accelerated conditions (temperature at 85°C and humidity at 85%). With the capping layer, the increase was from three-fold to ten-fold, depending on the number of transferred (and doped) layers. The importance of capping layers was also shown in the case of bending strain, where samples with capping layers shows only two- to three-fold increase in sheet resistance (0.58%-9.4% strain), whereas without capping layers the increase is > 46-fold at $\sim 5\%$ strain. The selectively transferred nanoparticles also increase the uniformity of sheet resistance, as is seen from the decrease of standard deviation from 54.89 to 12.73 Ω /sq. In the end, best figure of merit was 42.5 when using one graphene layer without capping and with three, and five-layers of graphene (and doping) figure of merit decreased to 29.9 and 31.1, respectively.

The standard wet transfer process for graphene uses a supporting polymer layer on top of the graphene, which allows the etching or delamination of the polymer/ graphene layers from the growth substrate. The supportive polymer is normally dissolved away after the transfer process. This technique commonly introduces folds and cracks on the graphene due to its non-rigid supportive polymer layer (commonly a thin layer of PMMA), and due to DI-water getting trapped in between the supportive polymer and the target substrate, even after drying. The folds and cracks can be reduced by using a more complex version of the transfer, where the target substrate is e.g., RCA (Radio Corporation of America) cleaned and HF dipped to increase hydrophobicity [110], or by a double PMMA deposition [111]. The use of PMMA as a supportive polymer also introduces residues on the graphene surface, which have been shown to affect transport properties [112]. The amount of residues can be reduced, for example, by using ultra-high vacuum annealing or annealing in H_2/Ar atmosphere [113,114], or by using a different supporting layer [115,116]. However, this process is easy to use and does not require any specialized equipment, making it a very common transfer technique. Furthermore, the supporting polymer makes a conformal contact with the graphene, reducing the number of holes in it after transfer to rigid substrates. Unfortunately, it is a very mechanical process and does not have a high throughput nor is it compatible with large-area processing. Also, while this method can be used for transferring graphene on arbitrary substrates, it is difficult to achieve a conformal transfer on non-rigid substrates [117].

Stamping method on the other hand is a dry-transfer (or semi-dry) method, minimizing polymer residues by skipping the polymer dissolving step entirely, opting for



Fig. 4 Defect healing scheme by Park et al., where gold nanoparticles are electroplated onto defected areas, increasing their conductivity. Adapted from Ref. [109]. (a) Schematic figure on where the gold nanoparticles coalesce after electroplating process. (b) Electroplating scheme of the gold nanoparticles

a mechanical removal process instead. PDMS is commonly used as the supportive layer and the increased rigidity of it in comparison to PMMA decreases the amount of folds and creases in the transferred graphene layer. The downsides being that the graphene layer can break because the PDMS is mechanically peeled away, and it is still not a residue-free process [118]. Also, this transfer method is not universal because it requires the adhesion force between graphene and the target substrate to be larger than in between graphene and PDMS. Furthermore, the target substrate should be rigid and clean in order to achieve a good conformal transfer. A modified version of this involves a secondary release layer in between the stamp and the graphene [118–120], allowing the transfer to a wider range of substrates.

Hot press lamination is a method, where the graphene is transferred directly from the growth substrate to the final substrate utilizing an adhesive layer that is melted and solidified by various means [103,106,117,121-123]. A similar method in comparison to the stamping method, but it usually utilizes higher temperatures and requires a separate machine for the transfer process. This process can be high-throughput and is applicable to large-area transfer if a roll-to-roll processing is applied, allowing transfer with minimal manual work. It is also compatible with growth substrate etching and electrochemical delamination, and can be used with a self-release layer, allowing full drytransfer [122]. However, this method can introduce voids and cracks in the graphene layer, possibly due to the nonconformality of the mechanical pressing (hot press or lamination between rollers) [124,125].

Electrochemical delamination is a version of the standard wet transfer where the growth substrate is not etched away, but instead, it is delaminated in an electrochemical cell. This method retains the growth substrate thereby substantially increasing the economy and ecology of the transfer process as the growth substrate can be re-used multiple times, potentially increasing the graphene quality in subsequent growth runs [126-128]. The original electrochemical delamination technique used H_2 bubbles to slowly peel the polymer/graphene layer from the growth substrate [127], but this easily introduces voids and cracks on the graphene due to vigorous hydrogen evolution, and due to H₂O permeating through the supporting polymer layer [129]. Second method is to use electrochemistry to reduce a copper oxide layer beneath the graphene, lowering the graphene adhesion enough that it readily peels off via surface tension [126,128]. Unfortunately, these electrochemical techniques need even more manual work than the standard etching method. Though it does have the potential for high-throughput processing due to its fast delamination (minutes instead of hours), but if the oxide reduction technique is used then the surface beneath graphene must be oxidized prior to transfer.

Graphene can also be grown using PECVD, where the growth temperatures can be lowered substantially by

lowering the energy barrier for hydrocarbon pyrolysis and dissociation. It can also be utilized for growing graphene on insulating substrates [130–133], skipping entirely the transfer process. Recently, PECVD has been used in conjunction with copper foam by Wei et al. to grow graphene on flexible glass [134]. This allows lower growth temperatures and the copper foam shielding the graphene from ion bombardment and smoothening the electric field. A RF plasma power of 80 W was used in Ar/H₂/CH₄ atmosphere in pressures of 2 Pa at low growth temperatures of 500°C–750°C. The grown graphene had transmittances between 68.5% and 89.5% and sheet resistances of 1.38–5.15 kΩ/sq, respectively, with the best figure of merit being $\sigma_{\rm DC}/\sigma_{\rm OP} = 0.66$.

In comparison to this, Chen et al. used RF plasma powers of 150 W at 600°C with glass substrates in Ar/H₂/ CH₄ atmosphere at pressures of 50 Pa [135]. The result was a graphene sheet with transmittance of 83.7% and sheet resistance of 661 Ω /sq, giving a figure of merit of σ_{DC}/σ_{OP} = 3.09.

A different approach was used by Vishwakarma et al. who realized CO₂ and O₃ enhanced PECVD graphene at low stage temperatures of 300°C using 1000 W microwave plasma in Ar/H₂/CH₄ atmosphere [136]. Low amounts of CO₂ (0.3 sccm) decreased sheet resistance of the graphene while only slightly decreasing transmittance, while O₃ improved both parameters by cleaning the graphene surface. Graphene was directly synthesized on glass and quartz substrates with final sheet resistance of 1.3 kΩ/sq and transmittance of 80%, resulting in a figure of merit of $\sigma_{\rm DC}/\sigma_{\rm OP} = 1.24$.

An extremely low substrate temperature (150°C) growth technique was adopted by Park et al. who used a thin (10 nm) Ti layer as a catalytic substrate on PET and glass, due to its strong affinity to carbon [137]. DC sputtered Ti layer was naturally oxidized into TiO₂ via exposure to atmospheric oxygen during sample transfer and it was reduced via annealing at 150°C in H₂ atmosphere. The growth was initiated by a 1100°C heating zone upstream of the growth substrate to decompose the hydrocarbon precursor (CH₄), the growth substrate itself was placed downstream at a 150°C zone at 0.6 Pa pressure in a CH₄/H₂ atmosphere. This technique resulted in graphene with transmittance of 97.5% and sheet resistance of 618 Ω /sq ($\sigma_{DC}/\sigma_{OP} = 24.1$).

This low-temperature growth technique was improved upon by Tran et al. who used the same technique, but the graphene growth and DC sputtering were done *in situ* and the thermal graphene growth was replaced with a plasma assisted CVD [138]. Using *in situ* system allowed avoiding the thermal reduction of TiO₂ and the plasma assisted CVD removed the need for a high-temperature CH₄ decomposition zone. The growth temperature was the same 150°C with the decomposition done in a horizontal 70 W RF plasma. This horizontal plasma avoids ion bombardment of the growth substrate. The graphene was grown in Ar/ CH₄/H₂ atmosphere at 2.4×10^2 Pa pressure and it had a remarkably low sheet resistance of 81 Ω /sq at 85.6% transmittance on a flexible polyestersulfone (PES) substrate (~87.8% of pure PES substrate) and extremely low I_D/I_G ratio of 0.01. This results in a figure of merit of $\sigma_{DC}/\sigma_{OP} = 29$.

Doping is an important aspect of transparent graphene electrodes, because it can be used to increase the conductivity of the sample with negligible effect on transparency. Gold chloride (AuCl₃) has been used widely as a p-type dopant for graphene. Different gold complexes (Au₂S, AuBr₃, Au(OH)₃) for graphene doping were investigated by Kwon et al. [139], because S, Br and OH have stronger bonds to gold than Cl, suggesting that S, Br and OH anions could improve the thermal stabilities of the Au complexes. It was found out that indeed the bond strength and electronegativity of the anion are related to the dopant's thermal stability; the Au(OH)₃ being the most stable on all measurements. Even though it was the most stable, it also provided the least amount of doping. This was measured from work function shift after the doping, where the work function increased from 4.3 to 5.0, 4.8, 4.6 and 4.9 eV, for AuBr₃, Au₂S, Au(OH)₃, and AuCl₃ dopants, respectively. This is also reflected in the sheet resistance measurements, where it decreased from 800-1100 to 530, 600, 820 and 300 Ω /sq with transmittances of 95%, 86%, 93% and 96% ($\sigma_{\rm DC}/\sigma_{\rm OP}$ = 13.7, 4.0, 6.2, 30.5) for AuBr₃, Au₂S, Au(OH)₃, and AuCl₃ dopants, respectively.

Jang et al. further expanded the study of doping graphene by comparing the time-evolution, structural, optical and electrical properties of three commonly used pdopants: HNO₃, AuCl₃ and RhCl₃ [140]. Each dopant introduced nanoparticles on the graphene surface, increasing the surface roughness from 0.34 to 1.88, 3.47 and 4.18 nm for HNO₃, RhCl₃ and AuCl₃, respectively. HNO₃ doping introduces smallest nanoparticles with smallest density. This is also reflected in the transmittance measurements, where the transmittance of pristine graphene 97.7% is decreased to 91%, 93% and 96% for AuCl₃, RhCl₃ and HNO₃, respectively. AuCl₃ and RhCl₃ are the most stable dopants, as their respective sheet resistances (500 and 220 Ω /sq) increased only 19% during a 20-day stability experiment, whereas HNO₃ increased up to 19%. It was concluded that RhCl₃ is the most stable dopant with the least degradation to transmittance and carrier mobilities.

The aforementioned doping methods have been for pdoping, but complementing this, Bult et al. tested hydrazine and polyethyleneimine (PEI) as n-type dopants for graphene [141]. It was observed that PEI has good stability in air, in comparison to hydrazine and that PEI results in similar doping levels and mobilities as hydrazine. All transfers were done using dry transfer via thermal release tape, instead of the more common wet transfer with PMMA. The resulting sheet resistance for four-layer hydrazine doped graphene is 50 Ω /sq with 89% transmission. For a single-layer, sheet resistances of 380 and 397 Ω /sq with transmittance of 96% were measured for hydrazine doping with PEI overcoat and for PEI-doped graphene, respectively. Doping had negligible effect on transmittance.

Generally doping is done chemically either after the growth, or during the growth via dopant gases. These methods use adsorbed species that are electron acceptors or donors, meaning that their long-term stability can be of problem due to desorption. Furthermore, the methods commonly incorporate foreign atoms on the graphene, making it difficult to reproduce [142]. Multiple other doping methods have been designed to mend these difficulties. Chae et al. sputtered aluminum nitride (AlN) layer on top of graphene to act as a buffer layer for evaporated nickel pads [143], see Fig. 5(a). Nickel atoms were injected from the pads to the graphene by applying voltages (3-5 V) through two separate pads, forming a conductive bridge between the two. The injected nickel atoms act as n-dopants, decreasing the sheet resistance from 712 \pm 75.2 to 216 \pm 46.1 Ω /sq with negligible effect on the transmittance of ~95% ($\sigma_{\rm DC}/\sigma_{\rm OP}$ = 33.6). The method indicated that no processing residues have remained, and that the nickel-atoms physically diffused into the graphene structure as intercalants. Another way of incorporating the dopants into the graphene structure is to use a plasma to break carbon bonds and replace the carbon atoms with a particular dopant, however, this process easily introduces defects on the graphene plane [144]. In order to decrease the amount of defects produced by plasma doping, Pham et al. used inductively coupled chlorine plasma with a dual metal mesh assembly, as shown in Fig. 5(b), designed to confine low-energy radicals to prevent damaging the graphene layer during the plasma treatment [16]. Sheet resistances of 305, 118 and 72 Ω /sq with transmissions of 98.2%, 97.3% and 95.64% were achieved for mono-, bi-, and tri-layer graphene, where the subsequent layers act as capping layers for the chlorine dopants. Undoped monolayer graphene showed sheet resistance of ~600 Ω /sq. No change in sheet resistance was found after four months in air environment for the bi- and tri-layer doped graphene (no data on monolayer). Figures of merit were 67.7, 115.9 and 116.2 for the mono-, bi- and tri-layer graphene, respectfully. Table 2 includes all the previously discussed results as well as multiple others with the best results having figures of merit over a hundred to up to over 400.

4 Applications

Graphene has many potential applications due to its unique properties. There is a need for new flexible and highly robust materials for next-generation electronics, and



Fig. 5 (a) Schematic of electrical injection of nickel atoms as p-type dopant by Chae et al., made with an AlN buffer layer. Adapted from Ref. [143]. (b) Chlorine doping of graphene in ICP by Pham et al., with two metal meshes to confine low energy radicals and protect the graphene layer. Adapted from Ref. [16]

graphene has both qualities. Transparency is interesting for semi-transparent solar cells and useful in display technologies. High surface-to-volume ratio is interesting in chemical reactions and battery technologies.

Solar cells are a particularly interesting application field for graphene as their commercial use has been increasing in the past decade. Graphene is a fantastic material for next-generation solar cells, for example, because of its flexibility, conductive properties, and transparency. High transparency is especially interesting in the field of semitransparent solar cells for building integrated photovoltaics (e.g., solar cells on windows). As has been previously mentioned in this work, ITO is prone to micro-cracks under bending which decrease its conductivity significantly. Furthermore, ITO can be problematic when using poly(styrenesulfonate) doped poly(3,4-ethylenedioxythiophene) (PEDOT:PSS), a common hole transport layer, because it has been shown to induce (reversible) cell degradation due to its acidity [155].

Polymer based solar cells are an attractive type of solar cells that can be ecological, cheap, and flexible [156,157], but having a smaller power conversion efficiency (PCE) than other solar cell types [158–160]. La Notte et al. used doped four-layer CVD graphene (on glass) as an ITO alternative in an inverted polymer solar cell with a common PEDOT:PSS layer to allow typical solution processing. Similar average PCEs were achieved using both transparent electrodes $(2.82\pm0.15\%)$ for graphene and $3.56\pm0.25\%$ for ITO) over eight devices [161]. An improved version on standard graphene/PEDOT:PSS can be done by introducing a MoO₃ electron blocking layer, which was shown by Park et al. [162], where over a tenfold improvement of PCE was achieved (from 0.5% to 7.1%) on a flexible substrate. PEDOT:PSS is a common hole transport layer, but functionalized graphene can be used instead of it as a hole transport layer, using for example, graphene oxide [163] or high sheet-resistance

CVD graphene [164]. Laser patterning of graphene is a well-established technique [165], and can be applied here as well, and oxygen-plasma can be used instead of chemical doping to increase wettability of the graphene laver, which increases the PCE [166]. Many other works on applications of graphene on polymer solar cells have been done, using it as an electrode layer [161,166–168], including it in a hybrid-polymer layer [169,170] or as hybrid electrode [171-174]. Graphene has also been applied to dye sensitized solar cells, e.g., in counterelectrodes [175–178], nanocomposite matrices [179,180] and photoanodes [181-183]. Another interesting thirdgeneration solar cell type is perovskite based solar cells (PSCs), which reached PCE of $\sim 25\%$ [184] in 2019, rivaling that of current commercial Si-based solar cells. PCEs are notorious for degrading (via e.g., light-induced degradation [185,186], humidity [187,188], and perovskite-metal reactions due to interdiffusion [189,190]), and even the best PSCs have lifetimes of only thousands of hours [191]. Graphene has been used as a stabilizing agent as, e.g., a protective layer [192–194], and transport layer [195–199] and electrode material [200–203].

Graphene is an interesting material in biosensing applications due to its two-dimensionality, or rather its lack of bulk, giving it extremely high surface-to-volume ratio. Potentially every single atom of the structure can be affected by an adsorbate, making graphene's inherent sensitivity high. Graphene based field-effect-transistor (GFET) sensor is a common and reliable sensor [204], and has been used recently e.g., for early detection of the Zika-virus [205], RNA and DNA detection down to 10^{-17} mol/L concentrations [206,207], *in operando* TEM measurements of neuropeptide capture and release [208] as well as detection of SARS-CoV-2 virus [209], the cause of the global COVID-19 pandemic of 2020. Other measurement schemes can be used as well, such as, Hall effect in standard [210], gated [211] and photonic spin [212,213]

$R_{\rm s}/(\Omega \cdot {\rm sq}^{-1})$	T/%	$\sigma_{\rm DC}/\sigma_{\rm OP}$	$R_{\rm change}$ /%	substrate	dopant (n/p)	Ref.
100	90	35	-	—	—	minimum industry requirement [70]
3600	85.7	0.66	_	flexible glass	_	[134] ^{a)}
1645	81	1.03	_	quartz	—	[104]
1300	80	1.24	_	quartz	_	[136] ^{a)}
1170	88	2.44	_	PET	-	[103]
661	83.7	3.09	_	glass	-	[135] ^{a)}
600	86	4.01	37	$SiO_2 (R_s)/glass (T)$	Au ₂ S (p)	[139]
230	71	4.39	_	PET	-	[145]
280	76	4.58	_	quartz	-	[98]
700	90	4.98	_	$SiO_2(R_s)/glass(T)$	_	[146]
350	83 ^{b)}	5.52	_	-	pyridine (n) ^{c)}	[147]
445	87	5.87	47	$SiO_2 (R_s)/PET (T)$	AuCl ₃ (p)	[148]
820	93	6.22	14	$SiO_2(R_s)/glass(T)$	Au(OH) ₃ (p)	[139]
1150	97	10.7	_	glass	_	[149]
200	86.7	12.7	87	EVA + PET	HNO ₃ (p)	[150]
530	95	13.7	44	$SiO_2 (R_s)/glass (T)$	AuBr ₃ (p)	[139]
350	93	14.6	52	_	RhCl ₃ (p)	[140]
150	87	17.4	66	$SiO_2 (R_s)/PET (T)$	AuCl ₃ (p)	[148]
220	91	17.8	70	_	AuCl ₃ (p)	[140]
500	96	18.3	32	_	HNO ₃ (p)	[140]
118 ^{d)}	84.9	18.7	56	glass	CsF (n)	[151]
129	88	22.1	70	$SiO_2 (R_s)/sapphire (T)$	TFSA (p) ^{e)}	[152]
550	97	22.3	_	PVDF ^{f)}	_	[153]
380	96	24.1	42	glass	hydrazine (n)	[141]
618	97.5	24.1	_	glass	_	[137] ^{a)}
500	97.1	25.4	_	quartz	_	[154]
299	95.7	28.4	62	$SiO_2 (R_s)/quartz (T)$	HNO ₃ (p)	[105]
81	85.6	29	_	PES ^{g)}	_	$[138]^{a)}$
300	96	30.5	68	$SiO_2 (R_s)/glass (T)$	AuCl ₃ (p)	[139]
216	95	33.6	70	quartz	Ni (p) ^{h)}	[143]
367	97.3	37.3	_	PET	_	[101]
215	96	42.5	44	$SiO_2(R_s)/glass(T)$	Au NP (p)	[109]
320	98	58.0	_	cellulose	_	[107]
50	89	62.8	76	glass	hydrazine (n)	[141]
305	98.2	67.7	49	PET	Cl plasma (p)	[16]
30 ^{d)}	90	116	25	$SiO_2 (R_s)/PET (T)$	$HNO_3(p)$	[106]
118 ⁱ⁾	97.3	116	80	PET	Cl plasma (p)	[16]
115	97.5	135	50	$SiO_2 (R_s)/PET (T)$	HNO ₃ (p)	[106]
25	96.5	419	83	parylene-C	$HNO_3(p)$	[108]

Table 2 Summary of different graphene based transparent electrodes, where R_s , T, σ_{DC}/σ_{OP} and R_{change} refer to sheet resistance, transmittance (at 550 nm unless otherwise specified), figure of merit and decrease of sheet resistance due to doping, respectively. Substrate refers to the substrate where R_s and T are measured on, if two substrates are given, then their corresponding measurements are given in brackets after the substrate

Notes: a) PECVD directly on dielectric substrate. b) At 633 nm. c) *In-situ* doping. d) Stacked four-layer graphene. e) Bis(trifluoromethanesulfonyl)amide. f) Polyvinylidene fluoride. g) Polyestersulfone. h) Doped via electrical injection. i) Stacked two-layer graphene

configurations or optical measurements using e.g., fluorescence [214,215], refractive index imaging [216] or surface plasmons [215,217–219]

Terahertz frequency photodetectors are important in many applications, such as, medicine [220], spectroscopy [221] and communications [222]. Its main benefits include its ability to penetrate most dielectrics without being invasive or ionizing, its capability to probe molecular dynamics [223] and the sheer data throughput for communications. Graphene has been used in these detection technologies in many ways e.g., as a ballistic rectifier [224], or on antennas on flexible substrates [225], or using more conventional GFETs [226–228]. Graphene has also been used in THz modulation [227,229].

Displays have integrated themselves in our society as computers have gained traction. Modern displays use technologies such as, organic light-emitting diodes (OLEDs), micro-LEDs, plasma, and liquid crystal displays (LCDs). Within these technologies, graphene has been used as an ITO replacement in standard [230,231] and flexible [232–234] OLED displays. Graphene has also been used in flexible alternating-current electrolumines-cent displays [235–237], as well as in LCDs [238–240]. Other applications of graphene in display technologies include increasing standard ITO OLED performance [241] and using as electrodes for GaN micro-LEDs [242].

5 Conclusions and outlook

Graphene is a one atom thick layer of carbon with multiple properties ideal for transparent electrodes. It is mechanically stable, flexible, optically near-transparent, and an excellent electrical conductor. Liquid exfoliation allows fast processing in bulk for fabricating graphene electrodes. Even though the best electrode properties rival that of CVD, liquid exfoliation still has multiple issues. Almost all the liquid exfoliation techniques use surfactants, organic solvents, or graphene oxide. Even liquid exfoliation in an electrochemical cell introduces a significant amount of oxides which ideally need to be reduced to their nonoxidized state. The glaring issue is that each technique requires high temperatures for defect removal which prevents their use on low-melting-point plastics. Chemical treatments can be used to reduce these temperatures, but the required temperatures are still above the melting points of common plastics. A way to circumvent the issues with high-temperature defect removal/reduction step, would be to use the high-temperature annealing on a rigid carrier from which the graphene is subsequently transferred to a flexible substrate. Unfortunately, this introduces another processing step and a transfer process generally introduces further basal-plane defects. Additionally, defect removal/ reduction step is not perfect and liquid exfoliated graphene is generally much more defective than CVD. Also, many of the discussed methods have a very long process time

(e.g., long-time sonication or centrifugation) in order to reach high enough graphene concentrations, or laterally large flakes or few-layer thicknesses. Tens or even hundreds of hours of processing time are problematic when the methods themselves do not scale up indefinitely. For instance, the energy transfer from a sonicator to the graphite flakes limits the processing volume of this method. Shear mixing scales much better, but it has been investigated much less than sonication. Toxic chemicals in Hummer's method for producing graphite oxide are also a problem for industry, as well is the cost of good solvents for pristine graphene. In the end, liquid exfoliation is an interesting technique due to its potential for massive production volumes but at its current state it introduces too many defects that require complicated processing to remove well. These issues might not be such a problem if the quality of the resulting film would reflect it; unfortunately, this is usually not the case. Some electrochemically produced graphene electrodes do have viable figures of merit, but they are still at least an order of magnitude away from being a viable ITO replacement.

CVD produces much higher quality graphene electrodes, many of the articles discussed in this review have figures of merit approaching and surpassing the minimum standard for industry. Unfortunately, for industrial adaptation, the result should be much better than the minimum standard for industry to abandon ITO. CVD has other issues as well; it is inherently expensive and does not scale as easily as liquid exfoliation. Graphene transfer process is also problematic. The use of metal etchants increase cost, and the manual transfer processes are a serious hindrance for large-scale production. Moreover, the transfer processes also introduce defects to the graphene lattice that can be problematic to remove adequately. However, the transfer process can be avoided if the growth is done directly on a dielectric substrate via PECVD, which would make the process much less manual and would increase the throughput substantially.

In the end, graphene shows excellent potential for transparent graphene electrodes, especially as flexible electronics are gaining traction. Future work on liquid exfoliation should be targeted towards new techniques or solvents that either intrinsically introduce less defects, or that remove defects (mainly oxides) more efficiently in order to increase the figure of merit high enough for industrial electrode applications. Furthermore, current reduction methods mainly involve high temperatures, thus lowering these while maintaining good reduction is imperative for industrial processing of flexible electronics. In CVD, the issues are the manual and mechanical transfer processes as well the loss of the growth substrate after etching. There is a need to research cleaner transfer processes that do not leave residues and are scalable for industrial use in thermal CVD processing. PECVD has major potential for removing many issues with thermal CVD regarding transfer processing, but it still requires

higher quality graphene to be competitive. Fortunately, the quality of PECVD graphene has improved substantially recently, which makes it a very valid industrial scale processing technique. The focus for PECVD should be to reduce the number of defects from the highly reactive and high velocity ions.

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